#### DESCRIPTION

The A2203 is a Class-AB audio power amplifier primarily designed for demanding mobile phones and other portable communication devices. It is capable of delivering 1.1 watts of continuous average power to an  $8\Omega$  BTL load with less than 1% distortion (THD+N) from a 5V<sub>DC</sub> power supply.

Boomer audio power amplifiers were designed specifically to provide high quality output power with a minimal amount of external components. The A2203 does not require output coupling capacitors or bootstrap capacitors. The A2203 is ideally suited for mobile phone, and other low voltage applications where minimal power consumption is a primary requirement.

The A2203 features a low-power consumption shutdown mode. To facilitate this, Shutdown may be enable by either logic high or low pending on mode selection. Driving the shutdown mode pin either high or low enable the shutdown pin to be driven in a likewise manner to enable shutdown.

The A2203 contains advanced pop-click circuitry which eliminates noise, which would otherwise occur during turn-on and turn-off transitions.

The A2203 is unity-gain stable and can be configured by external gain-setting resistors.

The A2203 is available in MSOP8 and SOP8 packages

# ORDERING INFORMATION

Package Type	Part Number				
MSOP8	MCO	A2203MS8R			
SPQ: 3,000pcs/Reel	MS8	A2203MS8VR			
SOP8	140	A2203M8R			
SPQ : 2,500pcs/Reel	M8	A2203M8VR			
Nete	V: Halogen free Package				
Note	R: Tape & Reel				
AiT provides all RoHS products					

#### **FEATURES**

- Ultra low shutdown current: 0.1uA (typ.)
- Improved PSRR at 217 Hz & 1 kHz: 60dB
- 2.2V ~ 5.5V operation
- Power output at 5.0V, 10%THD+N, 4Ω:
   1.7W(typ.) (SOP8 package)
- Power output at 5.0V, 1% THD+N, 8Ω:
   1.1W (typ.)
- 2.2V ~ 5.5V operation
- Unity-gain stable
- External gain configuration capability
- Improved circuitry eliminates pop-click noise during turn-on and turn-off transitions
- No output coupling capacitors, snubber networks or bootstrap capacitors required
- Available in MSOP8 and SOP8 Packages

#### APPLICATION

- Car Block Box
- Wireless handsets
- Portable electronic devices
- PDAs, Handheld computers

#### TYPICAL APPLICATION

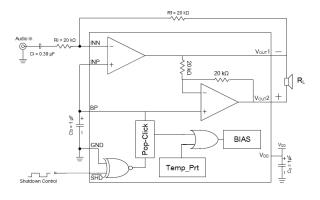
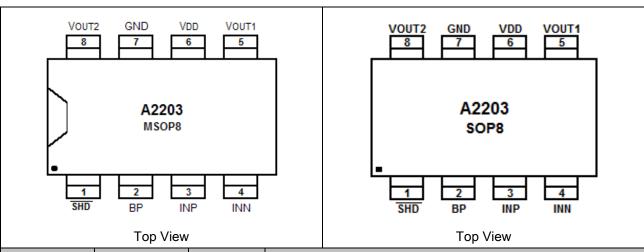


Figure 1

### PIN DESCRIPTION



Pin#	Symbol	1/0	Functions	
1	SHD	l	Shut-down Logical Control, '0' is active.	
2	BP	I/O	Analog ground for inner OPAs. It's about a half of V <sub>DD</sub> .	
3	INP	I	Positive Input	
4	INN	I	Negative Input	
5	V <sub>OUT1</sub>	0	Negative BTL Output	
6	$V_{DD}$	I/O	Power Supply (2.2 ~ 5.5 V)	
7	GND	I/O	Ground	
8	V <sub>OUT2</sub>	0	Positive BTL Output	

### ABSOLUTE MAXIMUM RATINGS

-0.3V~6V
-0.3V~V <sub>DD</sub> +0.3V
See Dissipation Rating Table
-40°C~+150°C
-65°C~+150°C
56°C/W
190°C/W
184°C/W
-40°C≦T <sub>A</sub> ≦85°C
2.2V≦V <sub>DD</sub> ≦5.5V

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

The following specifications apply for the circuit shown in Figure 1, unless otherwise specified. Limits apply for  $T_A = 25$ °C.

 $V_{DD} = 5V$ 

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Quiescent Power Supply	I <sub>DD</sub>	V <sub>IN</sub> =0V, 8Ω Load	ı	3.0	8	mA
Current		V <sub>IN</sub> =0V, No Load	-	2.5	7	mA
Shutdown Current	$I_{SD}$	V <sub>IN</sub> =0V, V <sub>SHD</sub> =GND, No Load	ı	0.1	2	μΑ
Shutdown Voltage Input High	V <sub>SDIH</sub>		1.2	-	ı	V
Shutdown Voltage Input Low	$V_{SDIL}$		ı	-	0.9	V
Output Offset Voltage	Vos		-50	6	50	mV
Total Harmonic	THD+N	D -0.5\\/	-	0.07	1	%
Distortion+Noise		Pout =0.5Wrms, f=1kHz				
Output Power	Po	THD+N<=1%, f=1kHz,	0.9	1.1	-	W
Output Fower		8Ω Load				
		Input terminated with $10\Omega$ ,		60	-	dB
B O I Britadia Balia	5055	V <sub>DDRIPPLE</sub> =0.2V <sub>P-P</sub> , f=217Hz	-			
Power Supply Rejection Ratio	PSRR	Input terminated with 10Ω,		61	-	4D
		V <sub>DDRIPPLE</sub> =0.2V <sub>P-P</sub> , f=1kHz				dB
Wake-up Time	<b>t</b> wu		-	100	-	ms

 $V_{DD} = 3V$ 

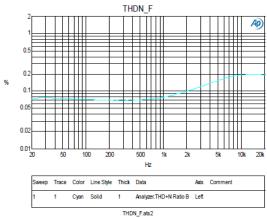
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Quiescent Power Supply	$I_{DD}$	V <sub>IN</sub> =0V, 8Ω Load	ı	2	7	mA
Current		V <sub>IN</sub> =0V, No Load	-	1.5	6	mA
Shutdown Current	$I_{SD}$	V <sub>IN</sub> =0V, V <sub>SHD</sub> =GND, No Load	ı	0.1	2	μΑ
Shutdown Voltage Input High	V <sub>SDIH</sub>		1.0	-	ı	V
Shutdown Voltage Input Low	$V_{SDIL}$		ı	-	0.7	V
Output Offset Voltage	Vos		-50	6	50	mV
Total Harmonic	THD+N	Pout=0.25Wrms, f=1kHz	-	0.08	-	%
Distortion+Noise		1 001 0.20 00000000000000000000000000000				
Output Power	Po	THD+N<=1%, f=1kHz,	-	310	-	mW
- Catpat i Siroi		8Ω Load				
	PSRR	Input terminated with 10Ω,		57	-	dB
Dawer Cumply Dejection Datio		V <sub>DDRIPPLE</sub> =0.2V <sub>P-P</sub> , f=217Hz	_			
Power Supply Rejection Ratio		Input terminated with 10Ω,		58		dB
		V <sub>DDRIPPLE</sub> =0.2V <sub>P-P</sub> , f=1kHz	-	50	-	uБ
Wake-up Time	twu		-	75	-	ms

#### $V_{DD} = 2.6V$

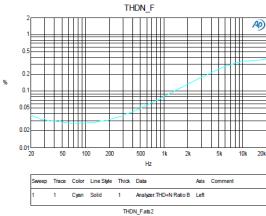
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Quiescent Power Supply	I	V <sub>IN</sub> = 0V, 8Ω Load	ı	1.7	-	mA
Current	I <sub>DD</sub>	V <sub>IN</sub> = 0V, No Load	ı	1.2	-	mA
Shutdown Current	I <sub>SD</sub>	V <sub>IN</sub> =0V, V <sub>SHD</sub> =GND, No Load	ı	0.1	-	μΑ
Shutdown Voltage Input High	V <sub>SDIH</sub>		1.0	-	-	V
Shutdown Voltage Input Low	V <sub>SDIL</sub>		-	-	0.7	V
Output Offset Voltage	Vos		-50	4	50	mV
Total Harmonic Distortion+Noise	THD+N	P <sub>OUT</sub> =0.15Wrms, f=1kHz	-	0.08	-	%
Output Power	Po	THD+N<=1%, f=1kHz, 8Ω Load	1	230	-	mW
Dower Cumby Dejection Datio	PSRR	Input terminated with 10Ω, VDDRIPPLE=0.2VP-P, f=217Hz	1	56	-	dB
Power Supply Rejection Ratio	PSKK	Input terminated with 10Ω, VDDRIPPLE=0.2VP-P, f=1kHz	-	57	-	dB
Wake-up Time	t <sub>WU</sub>		-	70	-	ms

#### TYPICAL PERFORMANCE CHARACTERISTICS

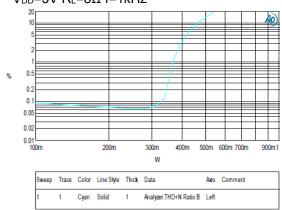
## 1. THDN vs. Frequency $V_{DD}$ =5V R<sub>L</sub>=8 $\Omega$ P<sub>O</sub>=500mW



## 3. THDN vs. Frequency $V_{DD}$ =2.6V R<sub>L</sub>=8 $\Omega$ Po=150mW

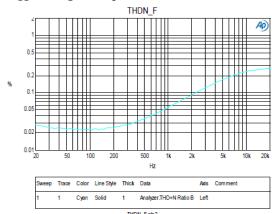


## 5. THDN vs. Output Power $V_{DD}=3V R_L=8\Omega f=1kHz$

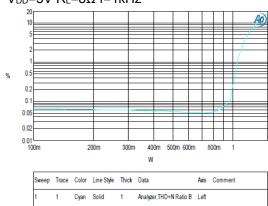


thdn\_po.ats2

## 2. THDN vs. Frequency $V_{DD}$ =3V R<sub>L</sub>=8 $\Omega$ P<sub>O</sub>=250mW

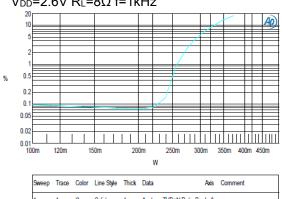


## 4. THDN vs. Output Power $V_{DD}$ =5V R<sub>L</sub>=8 $\Omega$ f=1kHz



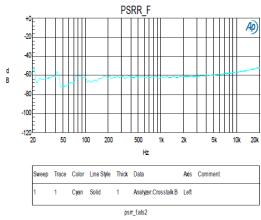
thdn\_po.ats2

## 6. THDN vs. Output Power $V_{DD}$ =2.6V $R_L$ =8 $\Omega$ f=1kHz

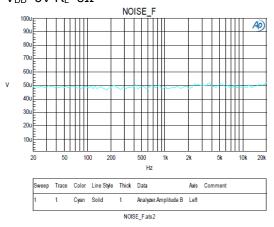


Sweep	Trace	Color	Line Style	Thick	Data	Axis	Comment
1	1	Cyan	Solid	1	Analyzer.THD+N Ratio B	Left	
				fhdr	n no ats2		

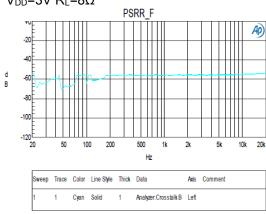
## 7. PSRR vs. Frequency $V_{DD}$ =5V $R_L$ =8 $\Omega$



## 9. Noise Floor 20kBW $V_{DD}$ =5V $R_L$ =8 $\Omega$



## 8. PSRR vs. Frequency $V_{DD}$ =3V $R_L$ =8 $\Omega$



#### **DETAILED INFORMATION**

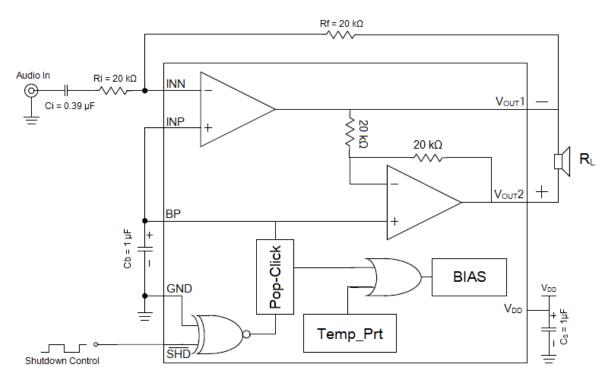


Figure. 1 A2203 Typical Application Circuit

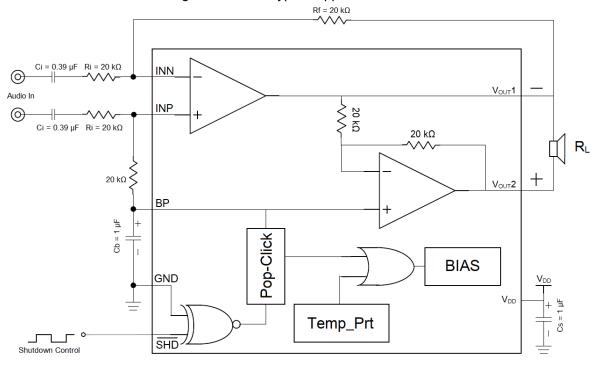


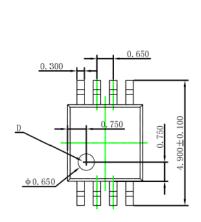
Figure. 2 A2203 Differential Amplifier Configuration

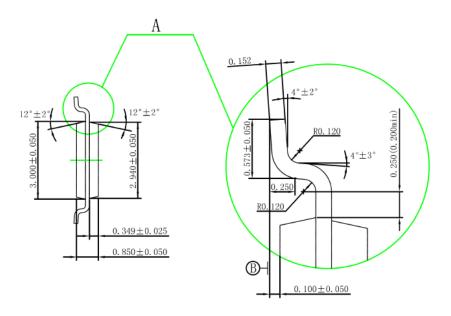
#### **External Components Description**

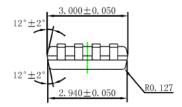
Components	Functional Description						
D:	Inverting input resistance which sets the closed-loop gain in conjunction with						
Ri	Rf. This resistor also forms a high pass filter with Ci at fc = $1/(2\pi Ri^*Ci)$ .						
O:	Input coupling capacitor which blocks the DC voltage at the amplifiers input						
Ci	terminates. Also creates a high-pass filter with Ri at fc = 1/(2πRi*Ci)						
Dt	Feedback resistance which sets the closed-loop gain in conjunction with Ri.						
Rf	The gain is A <sub>VD</sub> =2*(Rf/Ri).						
Cs Supply bypass capacitor which provides power supply filtering.							
Cb Bypass pin capacitor which provides half-supply filtering. Refer to the section.							

### PACKAGE INFORMATION

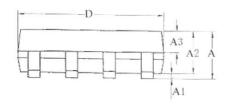
Dimension in MSOP8 (Unit: mm)

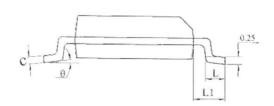


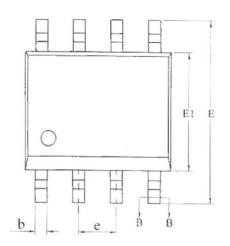


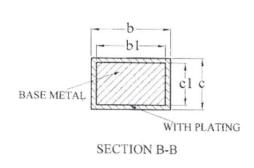


#### Dimension in SOP8 (Unit: mm)









Symbol	Min	Max			
А	-	1.77			
A1	0.08	0.28			
A2	1.20	1.60			
A3	0.55	0.75			
b	0.39	0.48			
b1	0.38	0.43			
С	0.21	0.26			
c1	0.19	0.21			
D	4.70	5.10			
Е	5.80	6.20			
E1	3.70	4.10			
е	1.27 BSC				
L	0.50	0.80			
L1	1.05 BSC				
θ	0°	8°			

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